NSN 5961-01-123-2084

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View Online at https://aerobasegroup.com/nsn/5961-01-123-2084 **Inclosure Material:** Metal **Overall Length:** 0.165 inches Overall Diameter: 0.225 inches **End Application:** 4920-01-054-8588 e/i fscm 81755 **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Press fit and unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage/static/emitter open and 22.0 collector to emitter voltage/static/base open and 3.3 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 150.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 2.7 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 12436-6011088 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 1 flange and 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: